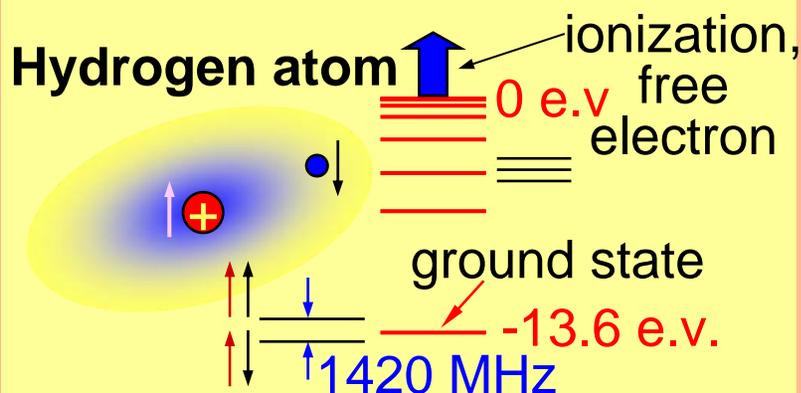


LASERS

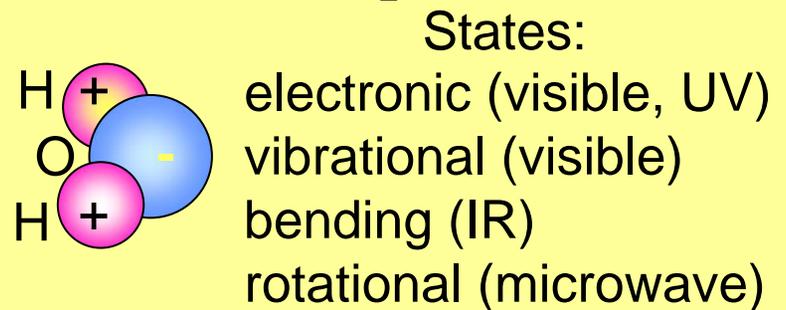
Representative applications:

- Amplifiers: Broad-band communications (avoid down-conversion)
- Oscillators: Frequency/distance reference, local oscillators, illuminators, transmitters, CD/DVD players, sensors
- Blasting: Laser machining, labeling, weapons, laser fusion (pellet compression). Peak $> 10^{15} \text{W}$, average $> 1 \text{kw}$; high intensity because $I \propto \left| \sum_i \bar{E}_i \right|^2$

Energy States:



Water vapor H_2O



Chromium atoms in lattice (e.g. ruby), Erbium atoms in glass

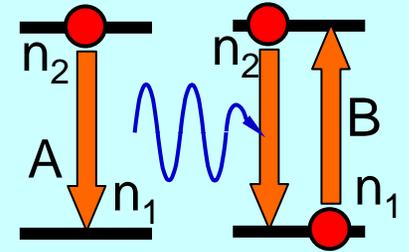
STIMULATED EMISSION AND ABSORPTION

Rate Equation:

Assume: Two-level system, $E_2 > E_1$, and $n_i =$ atoms m^{-1} in state i

Then: $dn_2/dt = - \underbrace{An_2}_{\text{Spontaneous emission}} - \underbrace{B(n_2 - n_1)}_{\text{Induced emission}} [m^{-1}s^{-1}]$ (collisionless system)

Spontaneous emission Induced emission



Spontaneous emission, states i to j :

$$A_{ij} = \omega^3 |D_{ij}|^2 (2/3h\epsilon c^3) [s^{-1}] \quad (\text{Decay time } \tau_A = A^{-1})$$

D_{ij} [C m] = quantum dipole moment (electric or magnetic)

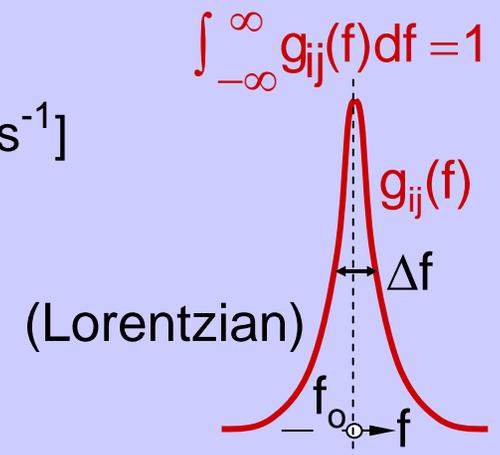
Note: $\tau_A \propto \omega^{-3} \Rightarrow$ very brief “visible” τ 's, long microwave τ 's

Stimulated emission and absorption:

Photon flux density F : $F = \frac{|E|^2}{2\eta_0 hf} [photons\ m^{-2}s^{-1}]$

B coefficient: $B_{ij} = F\sigma_{ij} \propto F g_{ij}(f) A_{ij}/\omega^3$

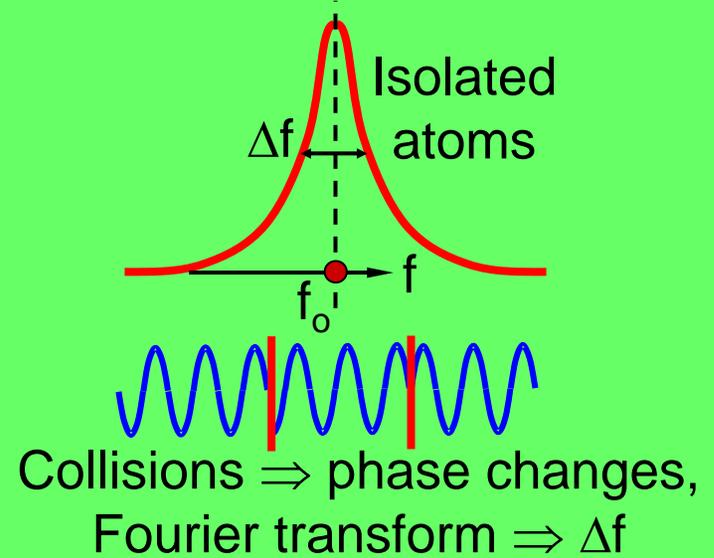
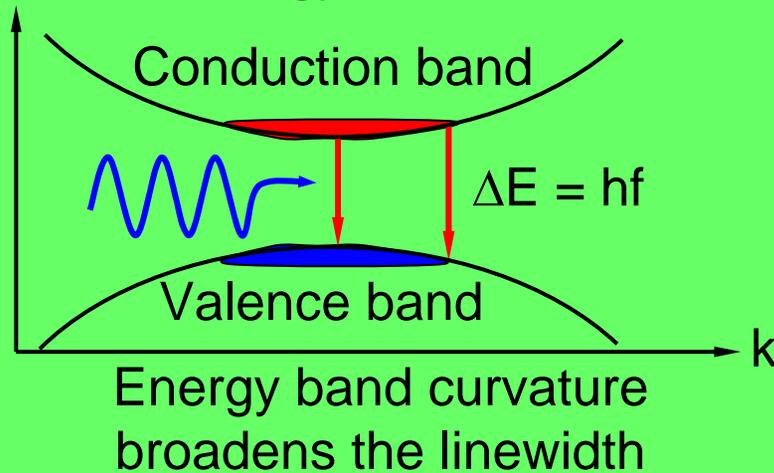
Line shape $g_{ij}(f)$:
$$g_{ij}(f) = \frac{2}{\pi \Delta f} \frac{1}{1 + 4 \frac{(f - f_0)^2}{(\Delta f)^2}}$$



ENERGY LEVEL POPULATION AND WIDTH

Linewidth Broadening Mechanisms:

Electron energy E in semiconductor



Level Populations—Kinetic Temperature T_k :

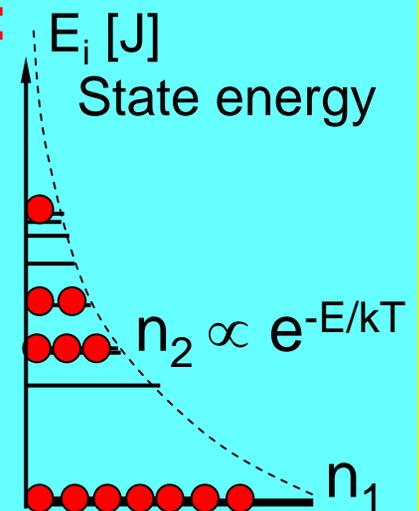
Thermal equilibrium \Rightarrow Boltzmann distribution: \Rightarrow

$$\frac{n_i}{n_j} = e^{-(E_i - E_j)/kT}$$

T = kinetic temperature if collisions dominate

T = radiation temperature if radiation dominates f_{ij}

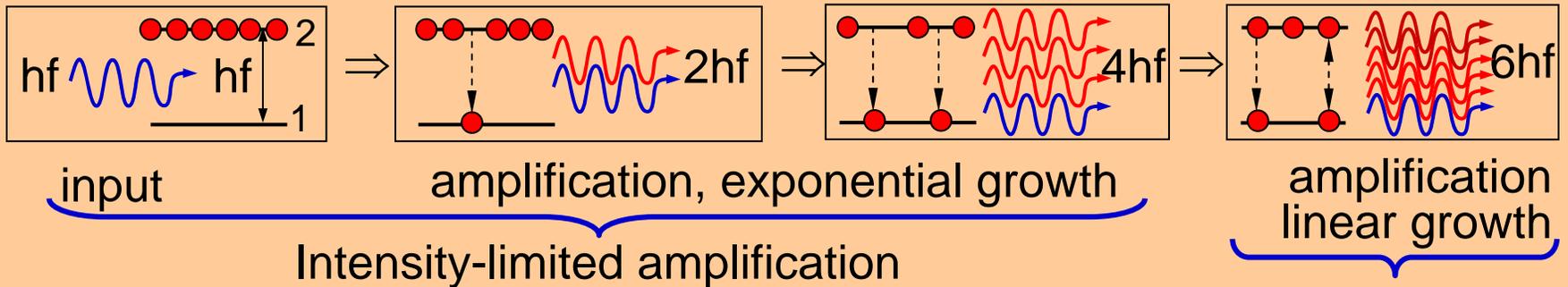
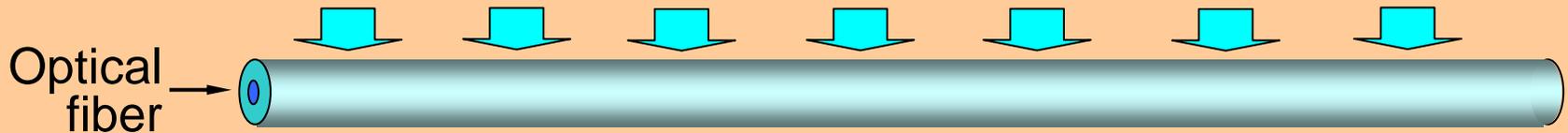
$$\Rightarrow n_i \rightarrow n_j \text{ if } T_{\text{rad}} \rightarrow \infty, n_2 > n_1 \text{ if } T_{\text{rad}} < 0$$



BASIC LASER AMPLIFIER PHYSICS

Amplification Process:

Pump (repopulates level 2)

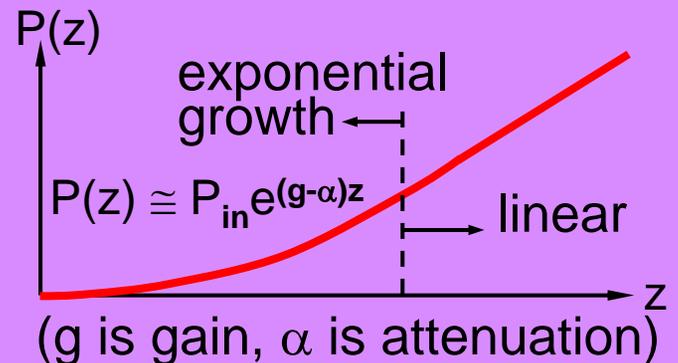


[Each \bullet is a separate atom or molecule;
need $n_2 > n_1$ for amplification]

Amplification frequency f [Hz]:

$$E_2 - E_1 = hf \text{ [J]},$$

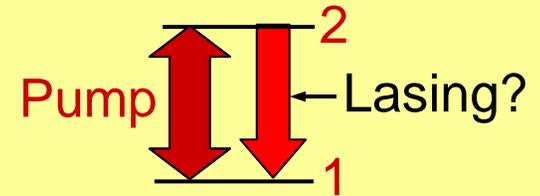
$$h = 6.625 \times 10^{-34} \text{ [Js]}$$



PUMPING OF LASERS

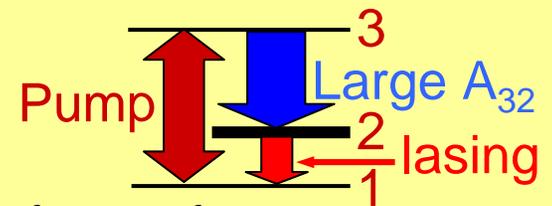
Two-Level Lasers:

Radiation pumping alone never yields $n_2 > n_1$
(some 2-level lasers spatially isolate n_2 group)

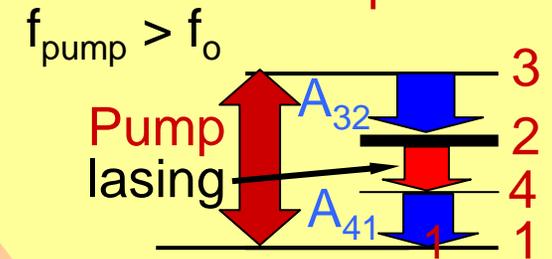


Three-Level Lasers:

Pumping the 1-3 transition yields $n_1 \cong n_3$
Large A_{32} populates L2 so $n_2 \gg n_1 \cong n_3 \cong 0$



More levels can utilize transitions with larger A's
Large A_{23} fills L_2 , and large A_{41} empties L_4



Laser Power Efficiency (P_{out}/P_{in}):

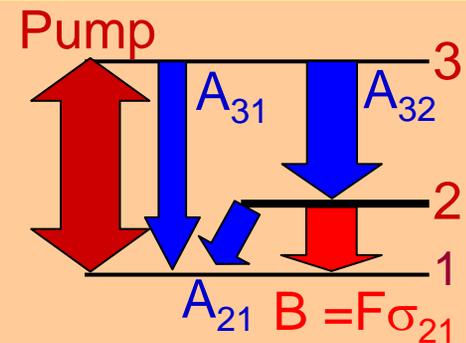
Intrinsic efficiency: $\eta_i = f_L/f_p$ ($P \propto nhf$ [W]) < 1

B/A efficiency @ 2: $\eta_B = B_{21}/(A_{21} + B_{21}) < 1$

A/A efficiency @ 3: $\eta_A = A_{32}/(A_{31} + A_{32}) < 1$

Total efficiency: $\eta = \eta_i \eta_B \eta_A$

Pump photons $s^{-1} \propto B \gg A \propto \omega^3$, so x-ray
lasers need pump power $\propto hfB \propto hfA \propto \omega^4$

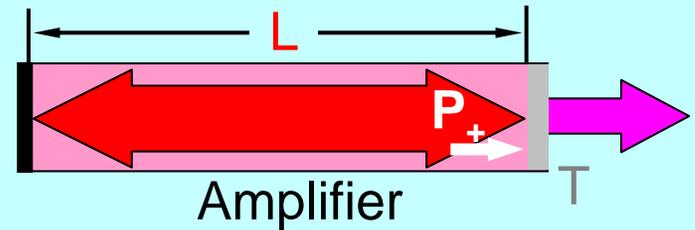


$$dn_2/dt = -An_2 - B(n_2 - n_1)$$

LASER OSCILLATORS

Laser Oscillation:

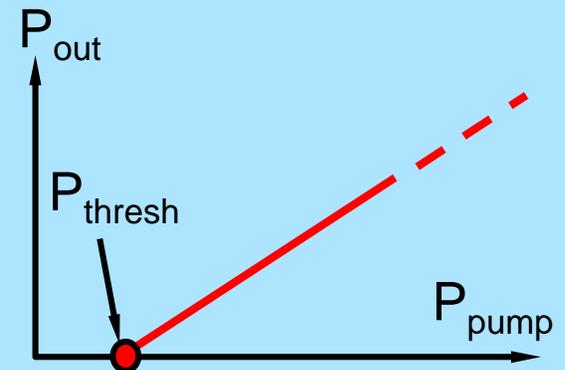
Lossless: With perfect mirrors at both ends a lossless amplifier must oscillate and saturate



Lossy: Round-trip gain must exceed round-trip loss (threshold condition); gain \propto pump power P_p , so need $P_p > P_{\text{thresh}}$

Mirrors: Exit mirror has power transmission coefficient $T > 0$
At threshold, Gain \cong Loss, so: $P_+(1 - T)e^{2(g-\alpha)L} \geq P_+$
 \Rightarrow round-trip gain = $e^{2(g-\alpha)L} \geq 1/(1 - T)$ for oscillation

Q-switching: Set mirror reflectivity low \Rightarrow round-trip gain $<$ threshold. When laser is fully pumped, increase mirror reflectivity over threshold, yielding very large “Q-switched pulse”



LASER RESONANCES

Oscillator Resonant Frequencies f :

Resonances

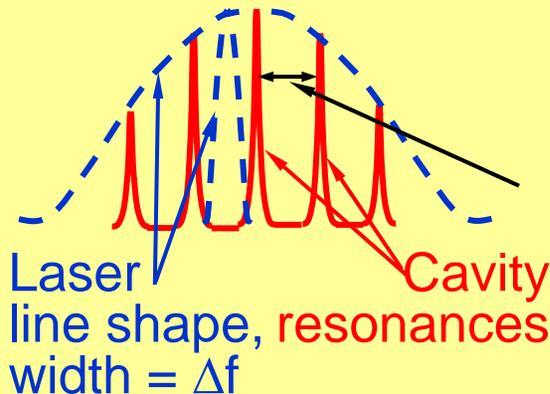
$$\frac{m\lambda_m}{2} = L \quad (\text{mirrors} \approx \text{short circuits})$$

$$\lambda_m = \frac{2L}{m}, \quad f_m = \frac{cm}{2LN} \quad (N = \text{refractive index})$$

$$f_{i+1} - f_i = \frac{c}{2LN}$$

$\cong 10^8$ Hz (100 MHz) for 1-meter fiber;

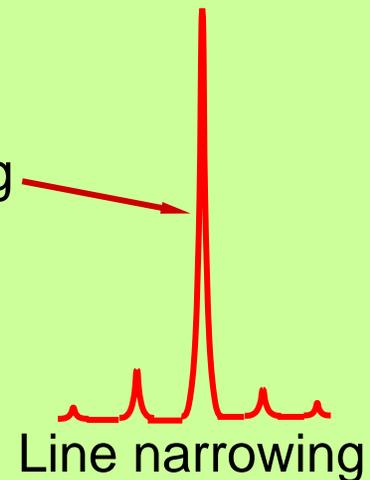
$\cong 50$ GHz line spacing for 0.5-mm diodes



Laser Output Spectrum:

If every atom can amplify at all frequencies, then the strongest round-trip gain wins \Rightarrow line narrowing (homogeneous line broadening)

If atoms can amplify only a portion of the band, then all lines over threshold can yield output (inhomogeneous line broadening)



EXAMPLES OF LASERS

Electrically Pumped Solid-State Lasers:

Forward-biased GaAs p-n junction
injects carriers into conduction band

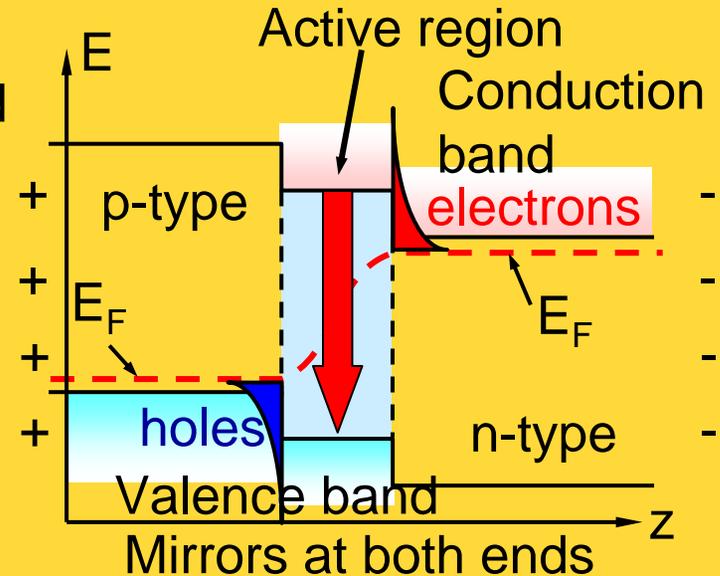
Compact (grain of sand)

~50 percent efficiency

>100 W/cm² for arrays

1 mW/micron² for diodes

1-1000 mW typical



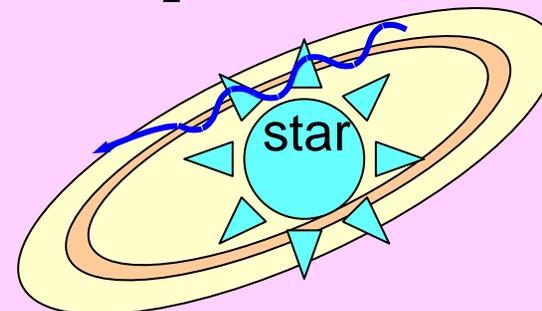
Astrophysical Masers:

Stellar Pumping: UV-IR pumped: H₂O, OH, CO, etc.

Interstellar collisions: OH, etc.

Chemical lasers:

Weapons (high energy, fast)



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Spring 2009

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